

# P38LF6QL

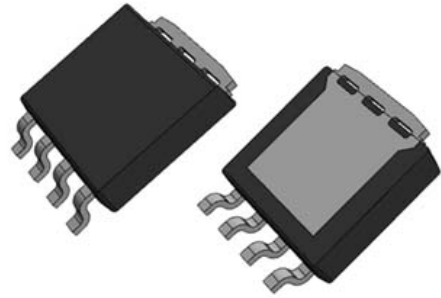
Power MOSFETs  
60V, 38A, N-channel

### Feature

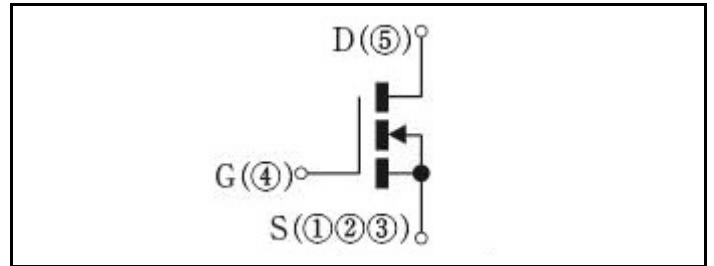
- N-channel
- Small SMD
- Low Ron
- 4.5V Gate Drive
- Low Capacitance
- Halogen free
- Pb free terminal
- RoHS:Yes

### OUTLINE

Package (House Name): LF  
Package (JEDEC Code): MO-235B similar



### Equivalent circuit



### Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

| Item                           | Symbol           | Conditions                   | Ratings    | Unit |
|--------------------------------|------------------|------------------------------|------------|------|
| Storage temperature            | Tstg             |                              | -55 to 175 | °C   |
| Channel temperature            | Tch              |                              | -55 to 175 | °C   |
| Drain-source voltage           | V <sub>DSS</sub> |                              | 60         | V    |
| Gate-source voltage            | V <sub>GSS</sub> |                              | ±20        | V    |
| Continuous drain current(DC)   | I <sub>D</sub>   |                              | 38         | A    |
| Continuous drain current(Peak) | I <sub>DP</sub>  | Pulse width 10μs, duty=1/100 | 114        | A    |
| Total power dissipation        | P <sub>T</sub>   |                              | 123        | W    |
| Single avalanche current       | I <sub>AS</sub>  | Starting Tch=25°C Tch≤150°C  | 22         | A    |
| Single avalanche energy        | E <sub>AS</sub>  | Starting Tch=25°C Tch≤150°C  | 57         | mJ   |

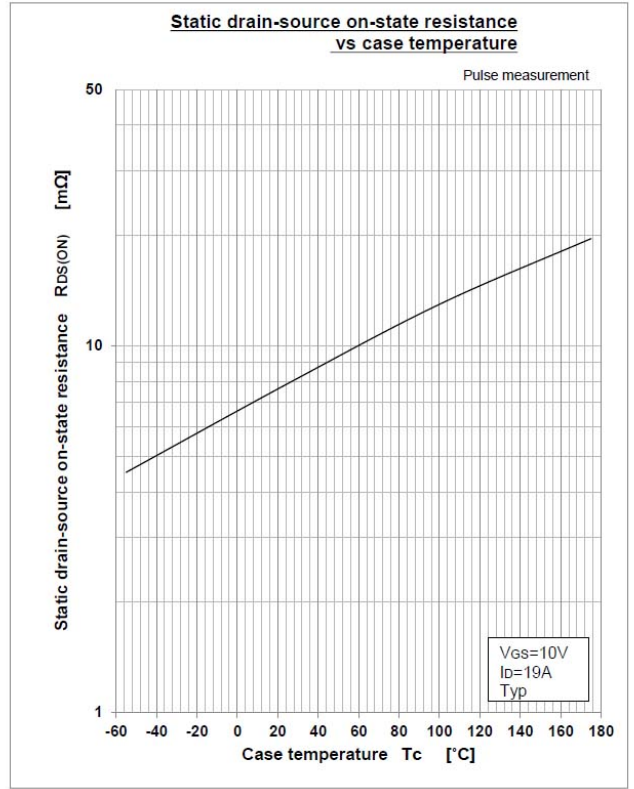
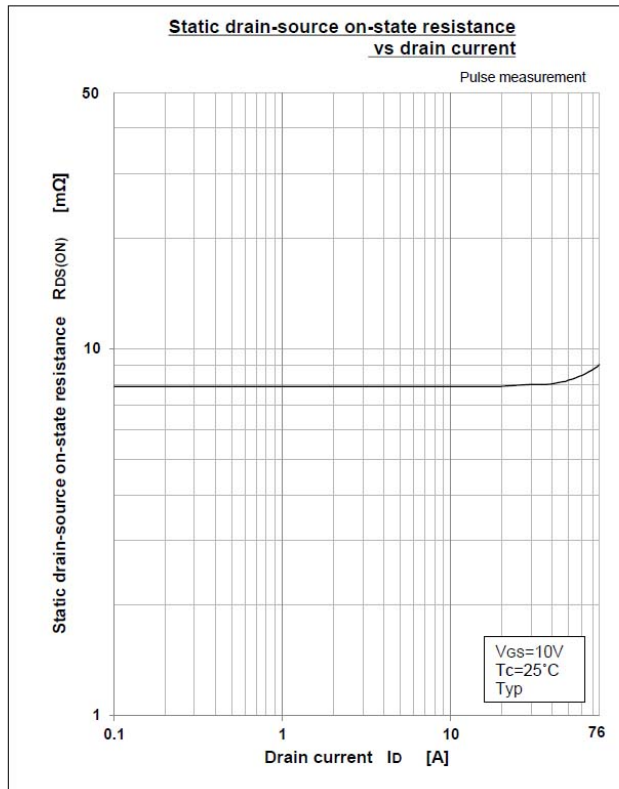
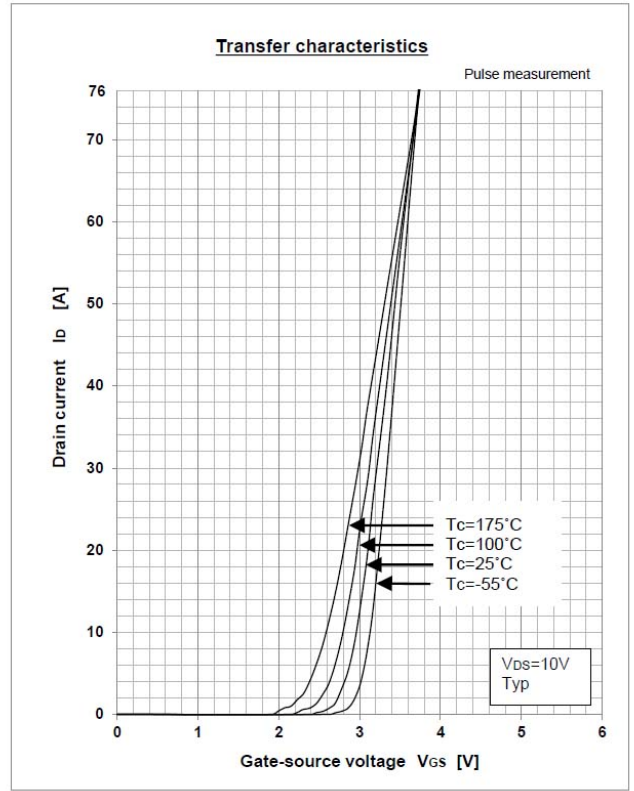
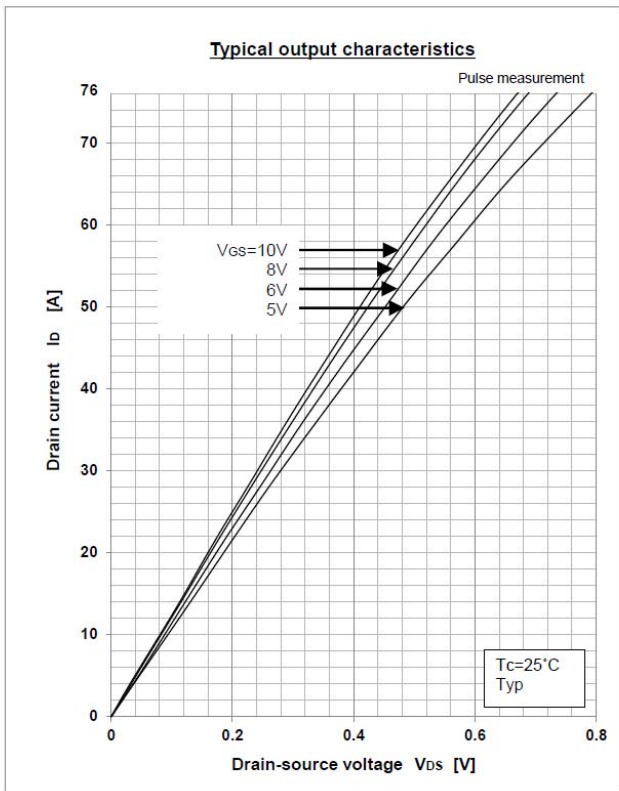
\* : See the original Specifications

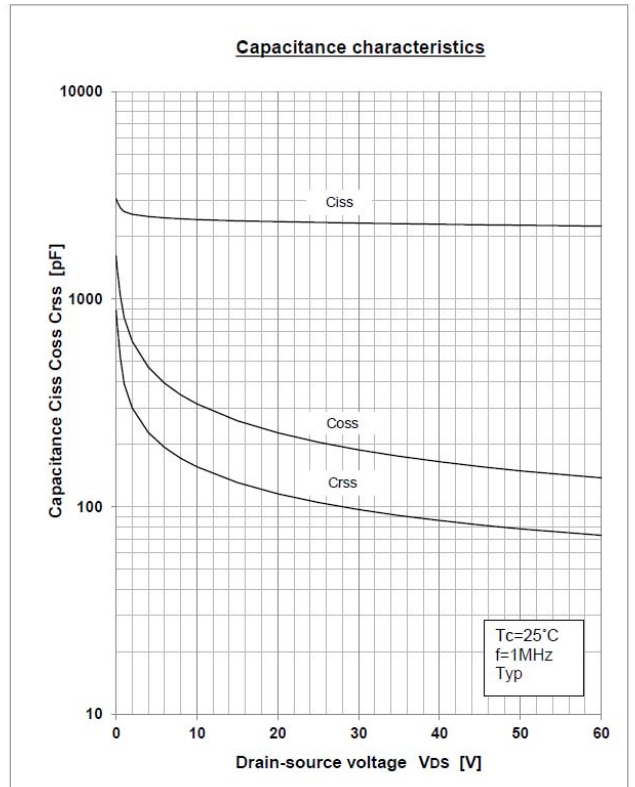
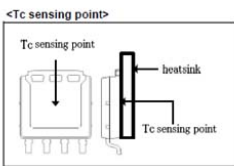
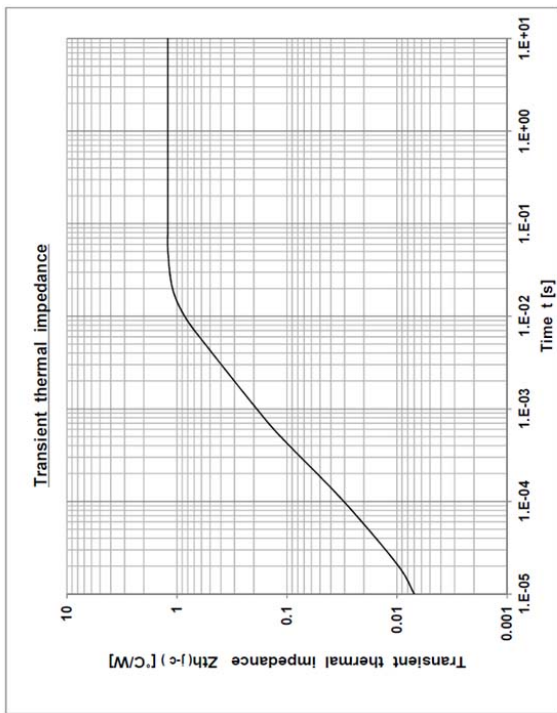
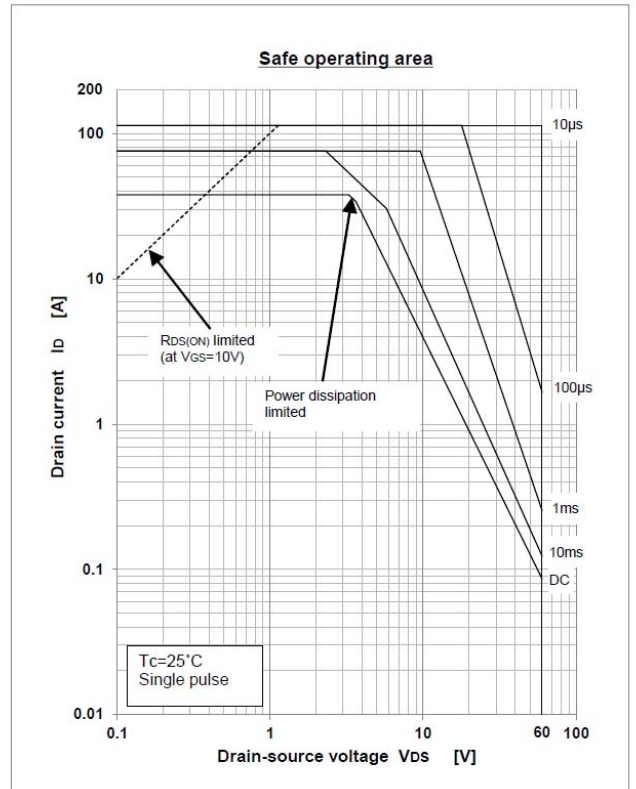
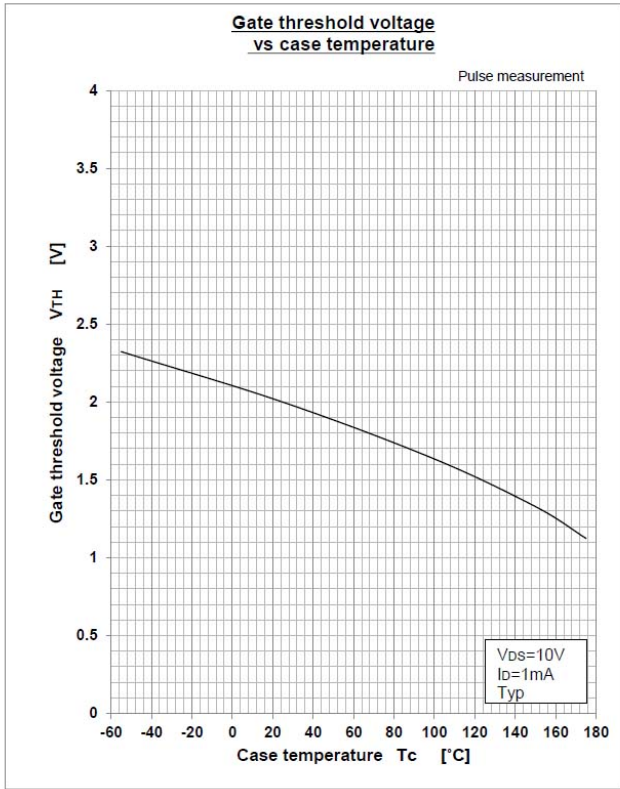
**Electrical Characteristics** (unless otherwise specified : Tc=25°C)

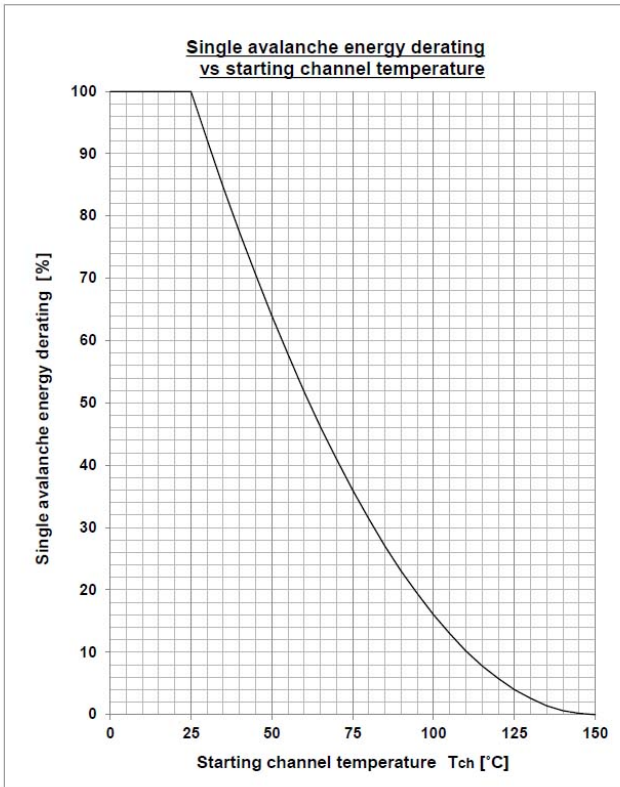
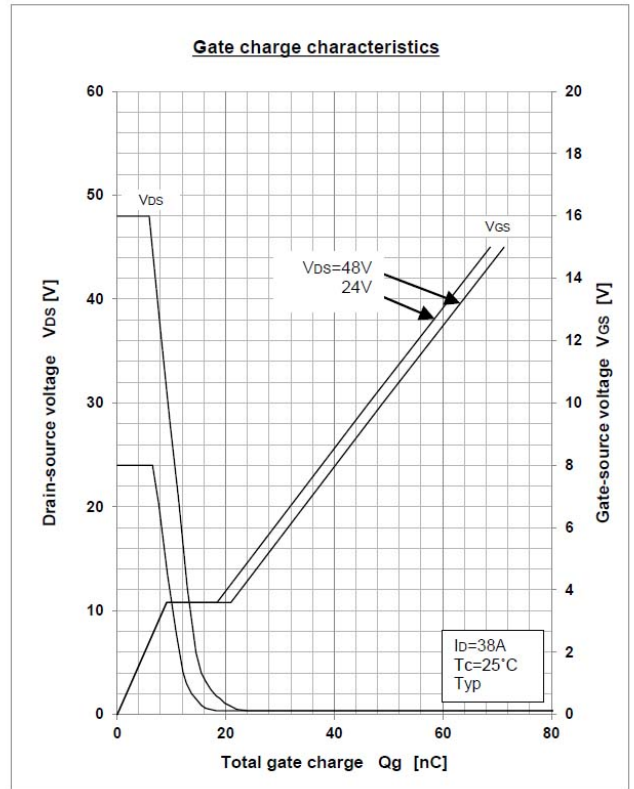
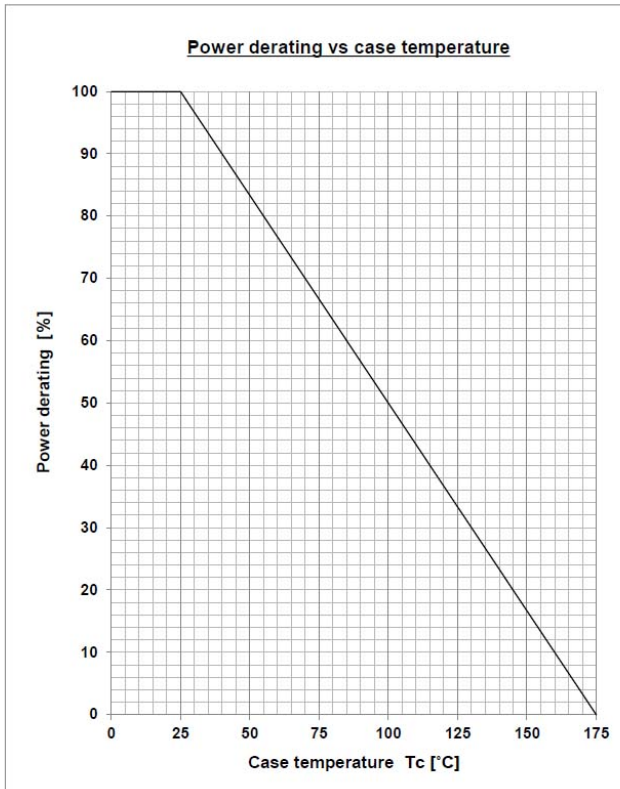
| Item                                    | Symbol        | Conditions   | Ratings |        |        | Unit |
|---|---------------|--|---------|--------|--------|------|
|   |               |  | MIN     | TYP    | MAX    |      |
| Drain-Source breakdown voltage          | $V_{(BR)DSS}$ | ID=1mA, VGS=0V   | 60      |        |        | V    |
| Zero gate voltage drain current         | $I_{DSS}$     | VDS=60V, VGS=0V  |         |        | 1      | μA   |
| Gate-source leakage current             | $I_{GSS}$     | VGS=±20V, VDS=0V                                       |         |        | ±0.1   | μA   |
| Forward transconductance                | $g_{fs}$      | ID=19A, VDS=10V  | 12      |        |        | S    |
| Static drain-source on-state resistance | $R_{DS(ON)}$  | ID=19A, VGS=10V  |         | 0.0079 | 0.0099 | Ω    |
| Static drain-source on-state resistance | $R_{DS(ON)}$  | ID=19A, VGS=4.5V                                       |         | 0.0097 | 0.0122 | Ω    |
| Gate threshold voltage                  | $V_{th}$      | ID=1mA, VDS=10V  | 1.5     | 2      | 2.5    | V    |
| Source-drain diode forward voltage      | $V_{SD}$      | IS=38A, VGS=0V   |         |        | 1.5    | V    |
| Thermal resistance                      | $R_{th(j-c)}$ | Junction to case, with heatsink                        |         |        | 1.21   | °C/W |
| Total gate charge                       | $Q_g$         | VDD=48V, VGS=10V, ID=38A                               |         | 49     |        | nC   |
| Gate to source charge                   | $Q_{gs}$      | VDD=48V, VGS=10V, ID=38A                               |         | 9.5    |        | nC   |
| Gate to drain charge                    | $Q_{gd}$      | VDD=48V, VGS=10V, ID=38A                               |         | 12     |        | nC   |
| Input capacitance                       | $C_{iss}$     | VDS=25V, VGS=0V, f=1MHz                                |         | 2340   |        | pF   |
| Reverse transfer capacitance            | $C_{rss}$     | VDS=25V, VGS=0V, f=1MHz                                |         | 105    |        | pF   |
| Output capacitance                      | $C_{oss}$     | VDS=25V, VGS=0V, f=1MHz                                |         | 205    |        | pF   |
| Turn-on delay time                      | $t_{d(on)}$   | ID=19A, RL=1.5Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V |         | 4.5    |        | ns   |
| Rise time                               | $t_r$         | ID=19A, RL=1.5Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V |         | 6      |        | ns   |
| Turn-off delay time                     | $t_{d(off)}$  | ID=19A, RL=1.5Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V |         | 28     |        | ns   |
| Fall time                               | $t_f$         | ID=19A, RL=1.5Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V |         | 6.5    |        | ns   |
| Diode reverse recovery time             | $t_{rr}$      | IF=38A, VGS=0V, di/dt=100A/μs                          |         | 40     |        | ns   |
| Diode reverse recovery charge           | $Q_{rr}$      | IF=38A, VGS=0V, di/dt=100A/μs                          |         | 44     |        | nC   |

\* : See the original Specifications

# CHARACTERISTIC DIAGRAMS

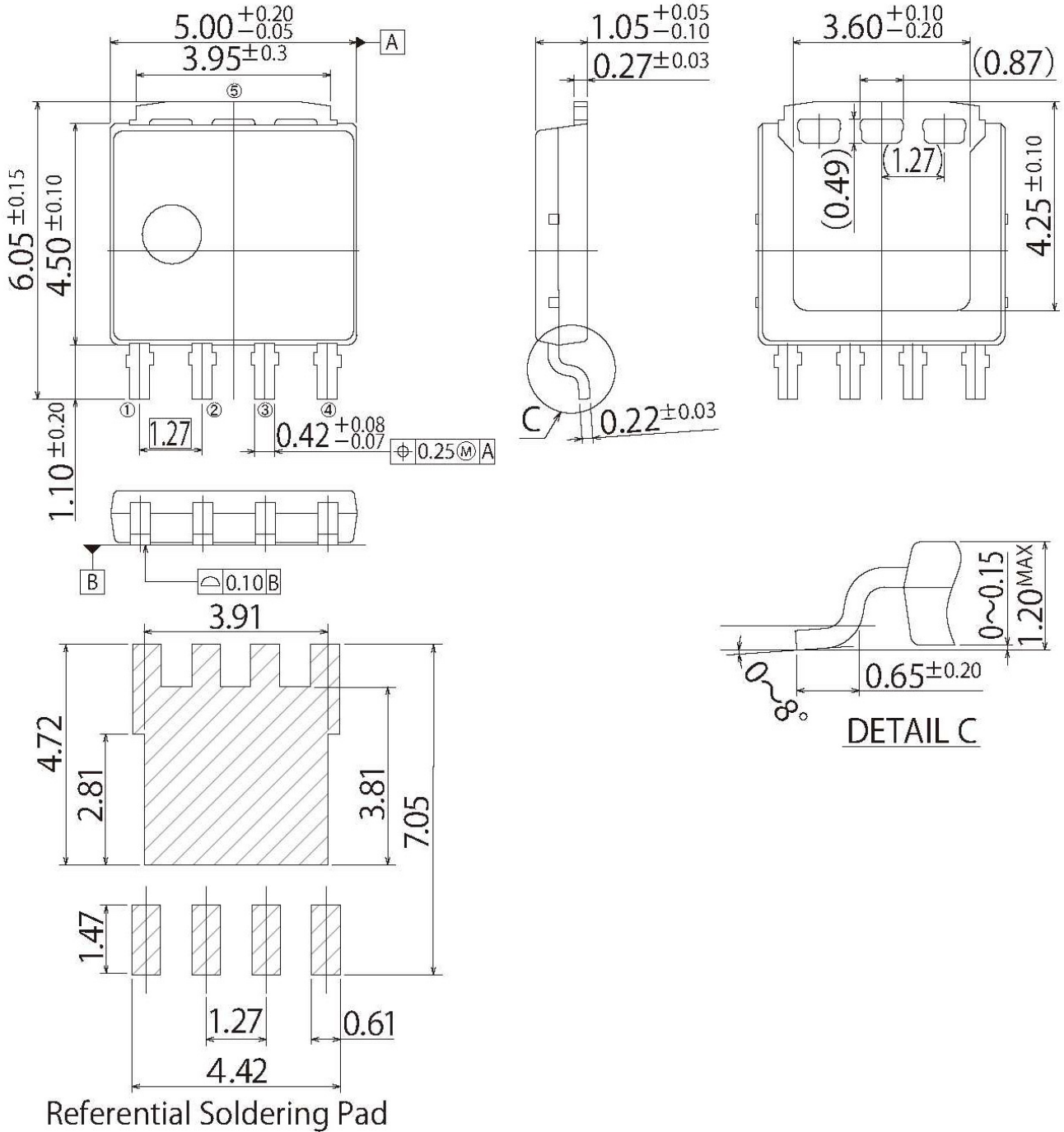






G7

|            |                 |
|------------|-----------------|
| JEDEC Code | MO-235B similar |
| JEITA Code | -               |
| House Name | LF              |



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